

Variation of Memory Cells on AGIPD02

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Outline

- Measurements
- Summary











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Measurement Concept

- 1) Writing all cells of one pixel at the same time
- Influence of test current source negligible
- 2) Reading the cells of one pixel
- 3) Comparing the output signals at the same sampling time



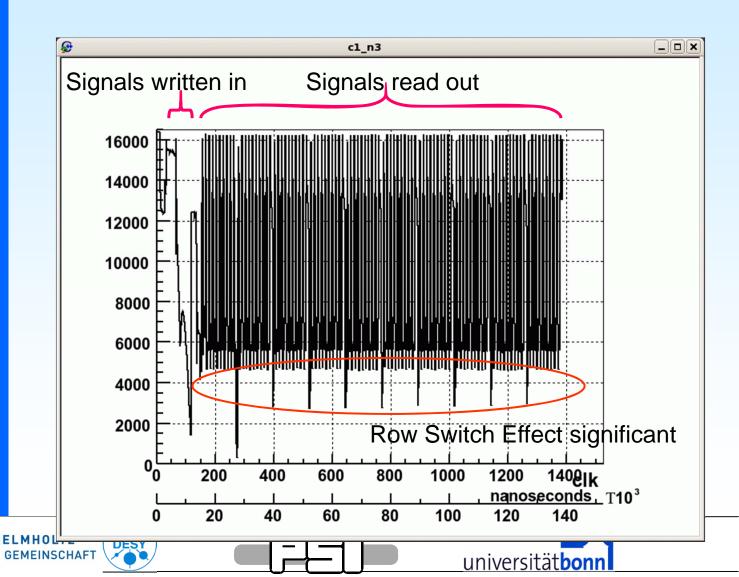






Measurements 10x10 Cells

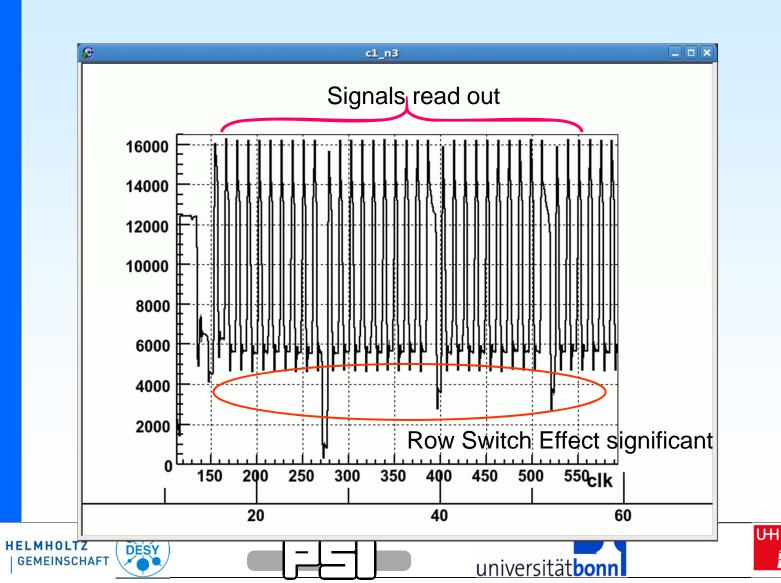




First 3x10 Cells (Zoom)

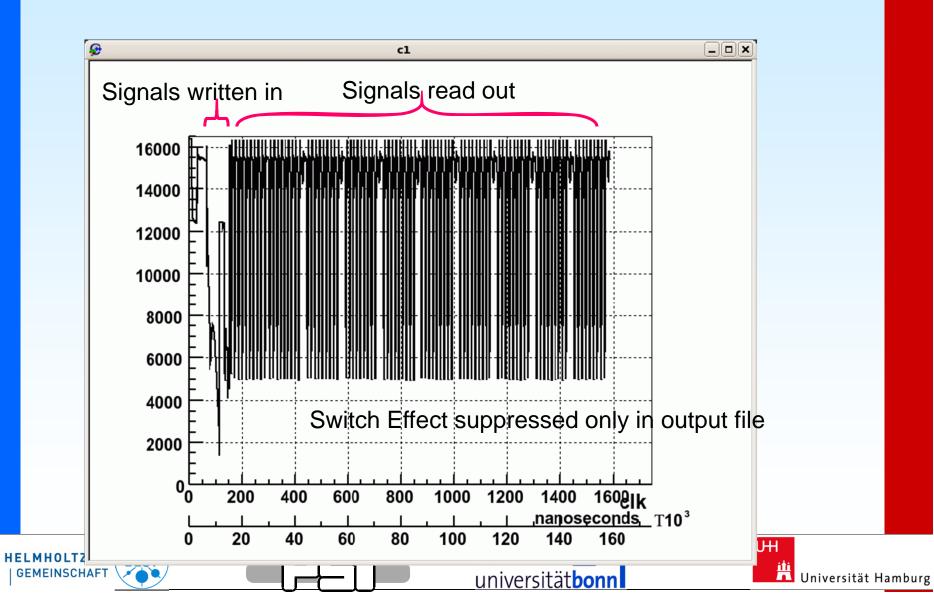


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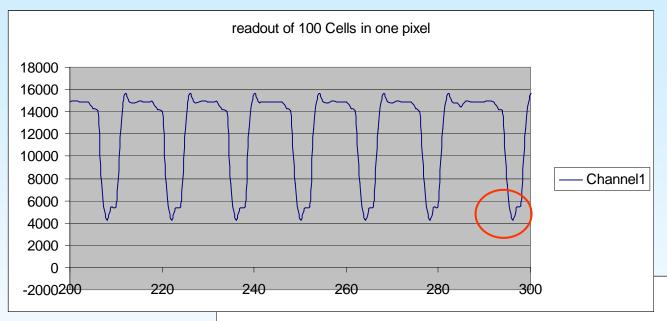
Measurements 10x9 Cells





Column 1-4: cell with pfet-dgncap





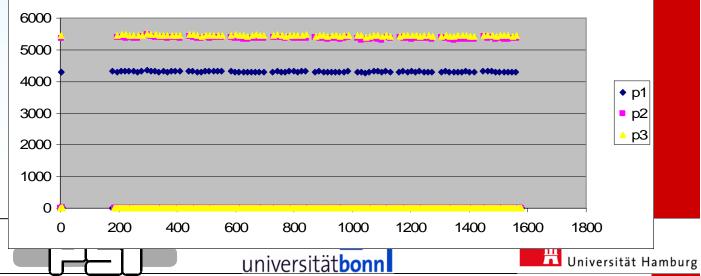
Switch effect from cell to cell still available;

Variation from cell to cell is tiny

P1	P2	P3
Median	Median	Median
4306	5365	5450
Mean	Mean	Mean
4307	5364	5448
StdDiv	StdDiv	StdDiv
15	28	20

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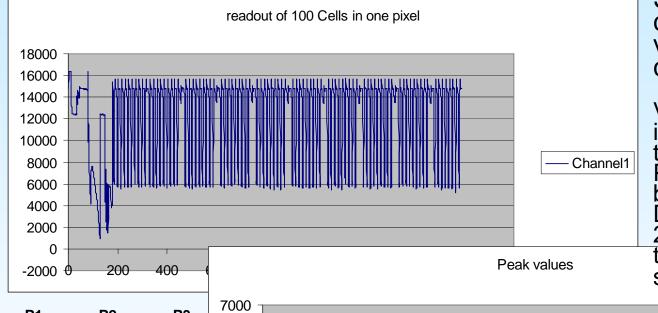
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Col 5-8: cell with dgpfet-dgncap



Switch effect comparable to variation of cells;

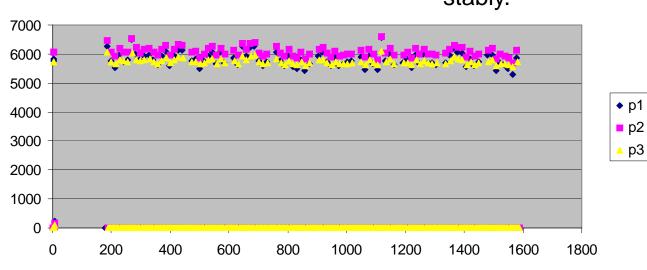
Variation of cells is much stronger than cells with PFET-switches, because the DGPFET needs 2.5V bias voltage to be working stably.



P1 **P2 P3** Median Median Median 5773 6047 5721 Mean Mean Mean 5813 6076 5739 **StdDiv StdDiv StdDiv** 237 164 101

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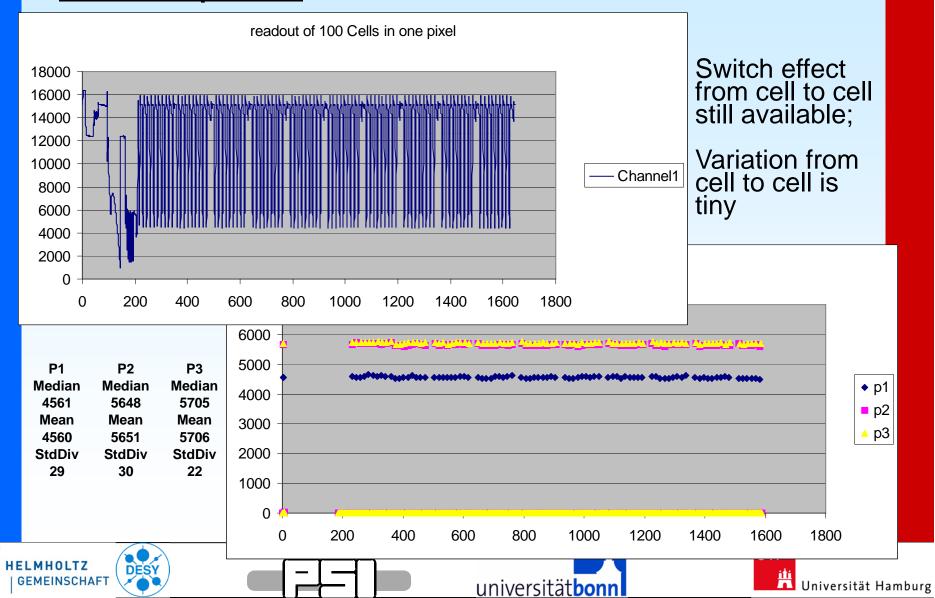
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Col. 9-12: cell with pfet-dgncap Pre-amp fast

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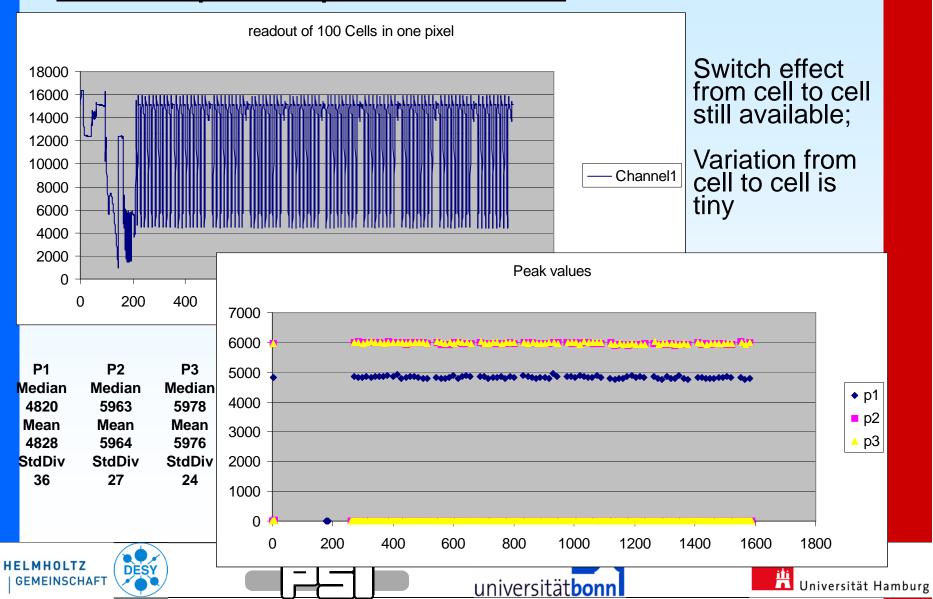




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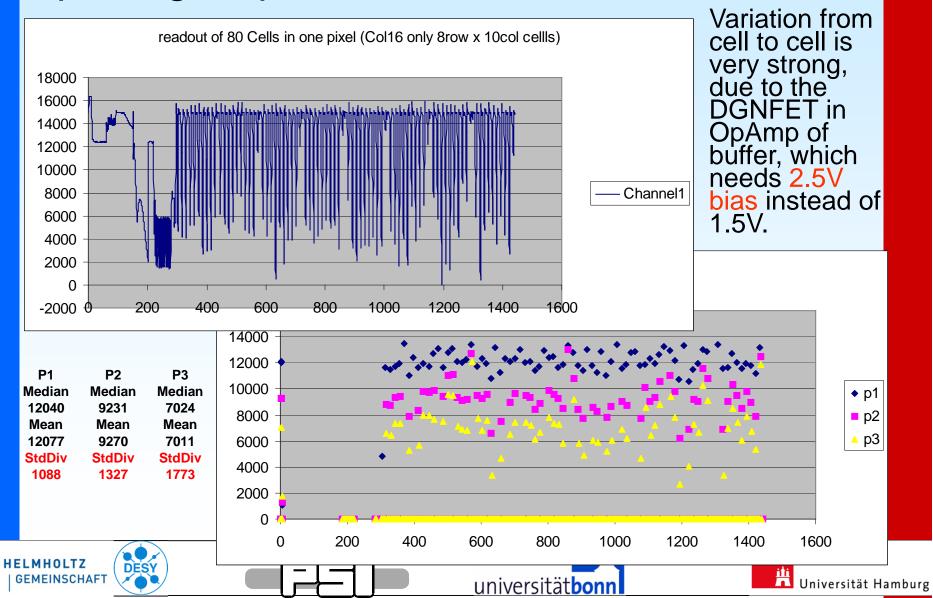
Col. 13-15: cell with pfet-dgncap Pre-amp with protect diode





Col. 16: 8row x 10col cells with pfet-dgncap, buffered





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Summary

- Cells with pfet-dgncap are stable enough
- Cells with dgpfet-dgncap are instable, because dgpfet needs higher bias voltage (2.5V) than applied in the measurement (1.5V)
- Difference of Preamps are not significant
- Buffered Cells are very instable (because DGNFET were used in the Op-Amp of buffer, which needs also 2.5V bias voltage)







